

SLWITOF .

IGBT module

SK 151 GB 07F3 T

Features

- Compact design
- One screw mounting module
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- 650V Fast Trench3 IGBT technology
- CAL diode technology
- Integrated NTC temperature sensor
- UL recognized, file no. E 63 532

Typical Applications*

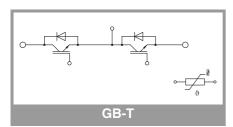
- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

Remarks

Dynamic measurements set-up:

- IGBT switching on external 150A 600V Ultrafast diode

- Diode switching on external 20A 600V Trench3 IGBT



Absolute	e Maximum Rating	gs		
Symbol	Conditions		Values	Unit
Inverter -	IGBT			
V _{CES}	T _j = 25 °C		650	V
lc	T _i = 175 °C	T _s = 25 °C	144	А
	1j = 175 C	T _s = 70 °C	114	А
I _{Cnom}			150	A
I _{CRM}	I _{CRM} = 3 x I _{Cnom}		450	Α
V _{GES}			-20 20	V
t _{psc}	$V_{CC} = 400 V$ $V_{GE} \le 15 V$ $V_{CES} \le 650 V$	T _j = 150 °C	5	μs
Tj		I	-40 175	°C
Inverse -	Diode			•
V _{RRM}	T _j = 25 °C		600	V
I _F	T 175 00	T _s = 25 °C	27	Α
T _j = 175 °C	T _s = 70 °C	21	Α	
I _{Fnom}		I	20	Α
I _{FRM}	$I_{FRM} = 2 \times I_{Fnom}$		40	Α
I _{FSM}	10 ms, sin 180°, 1	Г _ј = 150 °С	95	А
Tj			-40 175	°C
Module	•		·	•
I _{t(RMS)}			-	Α
T _{stg}			-40 125	°C
V _{isol}	AC, sinusoidal, t =	= 1 min	2500	V

Characteristics							
Symbol	Conditions		min.	typ.	max.	Unit	
Inverter -	IGBT						
V _{CE(sat)}	I _C = 150 A	T _j = 25 °C		1.85	2.22	V	
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.18	2.55	V	
V _{CE0}	chiplevel	T _j = 25 °C		1.10	1.20	V	
		T _j = 150 °C		1.00	1.10	V	
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		5.0	6.8	mΩ	
	chiplevel	T _j = 150 °C		7.9	9.7	mΩ	
V _{GE(th)}	$V_{GE} = V_{CE}$, $I_C = 2.4$ mA		4.2	5.1	5.6	V	
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 650 \text{ V}, \text{T}_{j} = 25 ^{\circ}\text{C}$				0.2	mA	
Cies	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		9.3		nF	
Coes		f = 1 MHz		0.348		nF	
C _{res}		f = 1 MHz		0.27		nF	
Q _G	V _{GE} = -15 +15 V			1380		nC	
R _{Gint}	T _j = 25 °C			1.6		Ω	
t _{d(on)}	$I_{\rm C} = 150 \text{ A}$ $R_{\rm G on} = 15 \Omega$ $R_{\rm C} = 15 \Omega$	T _j = 150 °C		153		ns	
tr		T _j = 150 °C		130		ns	
Eon		T _j = 150 °C		8.8		mJ	
t _{d(off)}		T _j = 150 °C		719		ns	
t _f		T _j = 150 °C		43		ns	
E _{off}		T _j = 150 °C		4		mJ	
R _{th(j-s)}	per IGBT			0.41		K/W	



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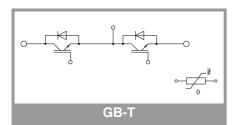
Remarks

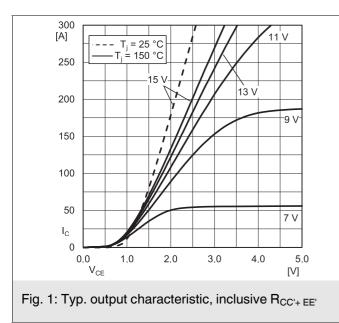
Dynamic measurements set-up:

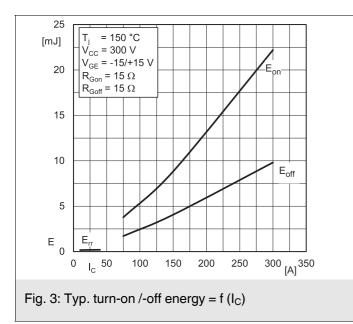
- IGBT switching on external 150A 600V Ultrafast diode

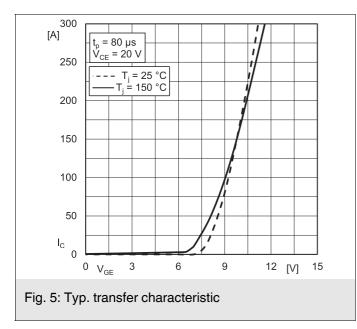
- Diode switching on external 20A 600V Trench3 IGBT

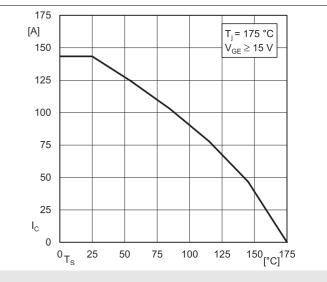
Characte	ristics					
Symbol	Conditions	min.	typ.	max.	Unit	
Inverse -	Diode					
$V_F = V_{EC}$	I _F = 20 A	T _j = 25 °C		1.59	2.06	V
	chiplevel	T _j = 150 °C		1.68	2.01	V
V _{F0}	chiplevel	T _j = 25 °C		0.99	1.10	V
		T _j = 150 °C		0.80	0.89	V
r _F	chiplevel	T _j = 25 °C		30	48	mΩ
		T _j = 150 °C		44	56	mΩ
I _{RRM}	di/dt _{off} = 3300 A/µs	T _j = 150 °C		32		Α
Q _{rr}		T _j = 150 °C		2		μC
E _{rr}	V _{GE} = 15 V V _{CC} = 300 V	T _j = 150 °C		0.2		mJ
R _{th(j-s)}	per Diode			2.46		K/W
Module		·				
L _{CE}				-		nH
Ms	to heatsink		2.25		2.5	Nm
w				29		g
Temperat	ure Sensor					
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω
B _{100/125}	R _(T) =R ₁₀₀ exp[B _{100/125} (1/T-1/T ₁₀₀)]; T[K];			3550 ±2%		к

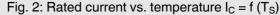


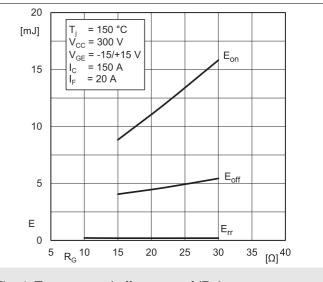


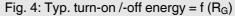


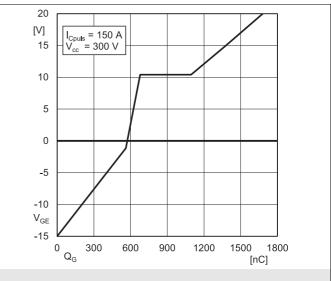


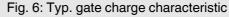


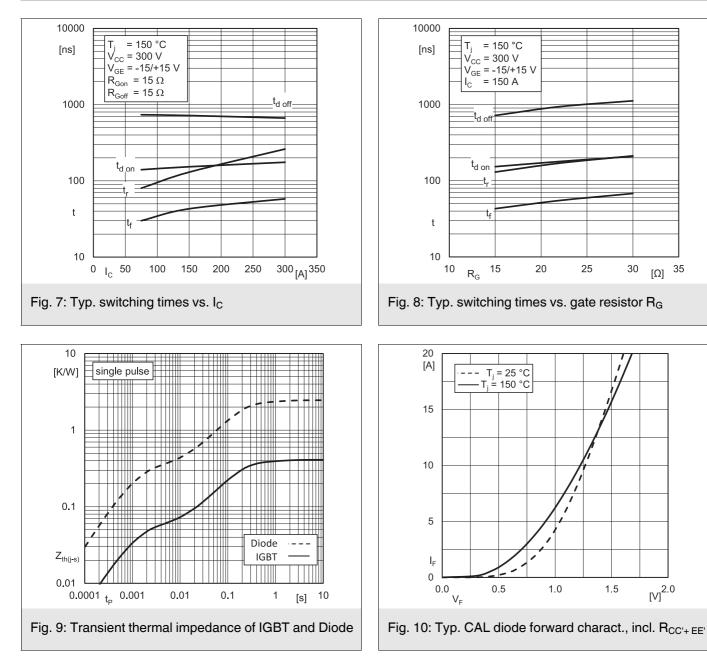


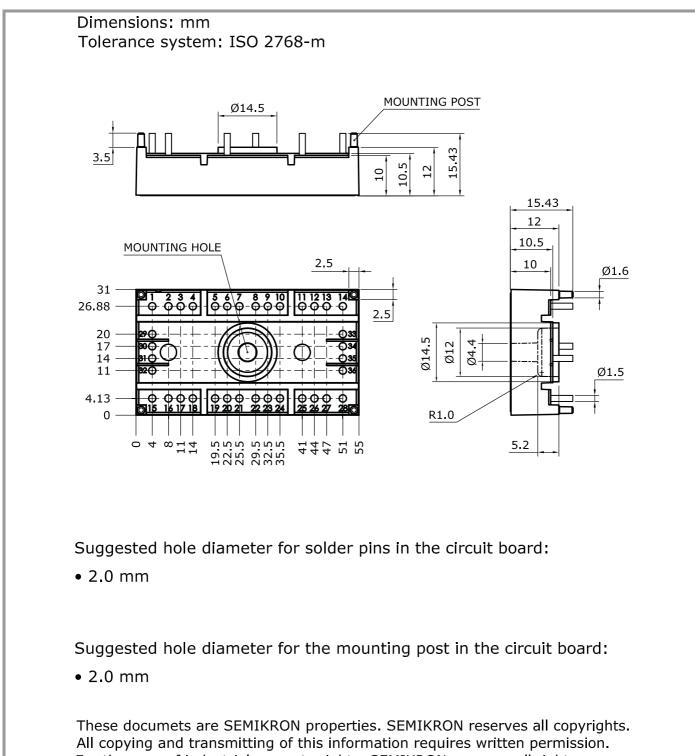






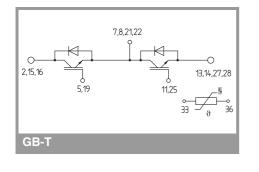






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SEMITOP[®]3



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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